

LOW POWER QUAD OPERATIONAL AMPLIFIER

DESCRIPTION

This circuit consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specially for automotive and industrial control systems. It operates from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the pow- er supply voltage.

FEATURES

Wide Gain Bandwidth: 1.3Mhz

Input Common-Mode Voltage Range Includes Ground

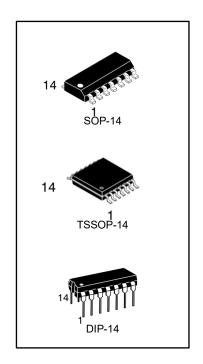
Large Voltage Gain: 100dB

Very Low Supply Current/Ampli: 375µA

Low Input Bias Current: 20nALow Input Offset Current:2nA

Wide Power Supply Range: Single Supply: +3V To +30V

Dual Supplies: ±1.5V To ±15V



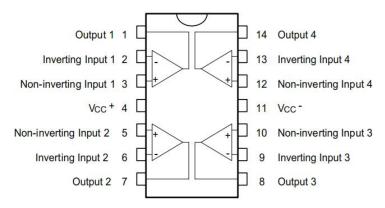
ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
LM2902PG	DIP-14	LM2902	TUBE	1000/box
LM2902DRG	SOP-14	LM2902	REEL	2500/reel
LM2902DRG4	SOP-14	LM2902	REEL	4000/reel
LM2902PWRG	TSSOP-14	LM2902	REEL	2500/reel

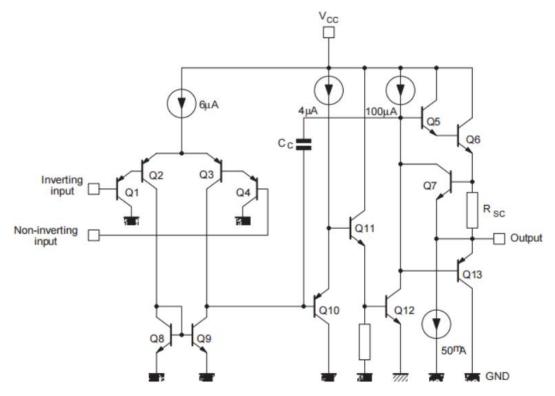


PIN CONNECTIONS (top view)

DIP-14/SOP-14/TSSOP- 14



SCHEMATIC DIAGRAM (1/4 LM2902)





ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Parameter	Value	Unit
VCC	Supply Voltage	±16 to 32	V
Vid	Differential Input Voltage	+32	V
VI	Input Voltage	-0.3 to +32	V
	Output Short-circuit to Ground ²⁾	Infinite	
Diat	Power Dissipation N Suffix	500	mW
Ptot	D Suffix	400	11100
l _{in}	Input Current ³⁾	50	mA
T _{oper}	Operating Free-Air Temperature Range	-40 to +85	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (Soldering, 10 seconds)	245	°C

- Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.
- 2. Short-circuit from the output to VCC can cause excessive heating if VCC > 15V. The maximum output current is approximately 40mA independent of the magnitude of VCC. Destructive dissipation can result from simultaneous short-circuit on all amplifiers.
- 3. This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward biased and thereby acting as input diodes clamps. In addition to this diode action, there is also NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the Op-Amps to go to the VCC voltage level (or to ground for a large overdrive) for the time duration than an input is driven negative. This is not destructive and normal output will set up again for input voltage higher than -0.3V.



ELECTRICAL CHARACTERISTICS

VCC+ = 5V, Vcc- = Ground, VO = 1.4V, Tamb = 25°C (unless otherwise specified)

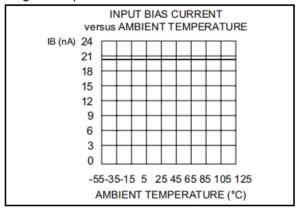
Symbol	Parameter	Min.	Тур.	Max.	Unit
Vio	Input Offset Voltage ¹⁾ Tamb = +25°C Tmin ≤ Tamb ≤ Tmax.		2	7 9	mV
l _{io}	Input Offset CurrentT _{amb} = +25°C T _{min} ≤ T _{amb} ≤ T _{max} .		2	30 40	nA
l _{ib}	Input Bias Current ²⁾ Tamb = +25°C Tmin ≤ Tamb ≤ Tmax.		20	150 300	nA
A _{vd}	Large Signal Voltage Gain V_{CC}^+ = +15V,RL =2k Ω , VO = 1.4V to 11.4V T_{amb} = +25°C $T_{min} \le T_{amb} \le T_{max}$.	50 25	100		V/mV
SVR	Supply Voltage Rejection Ratio (Rs \leq 10k Ω)T _{amb} = +25°C T _{min} \leq T _{amb} \leq T _{max} .	65 65	110		dB
Icc	Supply Current, all Amp, no load $T_{amb} = +25^{\circ}C \qquad V_{CC} = +5V$ $T_{min} \le T_{amb} \le T_{max}. V_{CC} = +30V$ $V_{CC} = +5V$ $V_{CC} = +30V$		0.7 1.5 0.8 1.5	1.2 3 1.2 3	mA
V _{icm}	Input Common Mode Voltage Range (V _{CC} = +30V) ³⁾ T _{amb} = +25°C T _{min} ≤ T _{amb} ≤ T _{max} .	0 0		Vcc -1.5 Vcc -2	V
CMR	Common-mode Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$.	70 60	80		dB
lo	Output Short-circuit Current($V_{id} = +1V$) $V_{CC} = +15V$, $V_{O} = +2V$	20	40	70	mA
Isink	Output Sink Current ($V_{id} = -1V$) $V_{CC} = +15V$, $V_{O} = +2V$ $V_{CC} = +15V$, $V_{O} = +0.2V$	10 12	20 50		mΑ μΑ
Vон	High Level Output Voltage (V_{cc} + 30V) T_{amb} = +25°C R_L = 2k Ω $T_{min} \le T_{amb} \le T_{max}$. T_{amb} = +25°C R_L = 10k Ω $T_{min} \le T_{amb} \le T_{max}$. (V_{cc} + 5V), R_L = 2k Ω $T_{min} \le T_{amb} \le T_{max}$. T_{amb} = +25°C	26 26 27 27 3.5 3	27 28		V
VOL	Low Level Output Voltage (R _L = $10k\Omega$)T _{amb} = $+25^{\circ}$ C T _{min} \leq T _{amb} \leq T _{max}		5	20 20	mV
SR	Slew Rate V_{cc} = 15V, Vi = 0.5 to 3V, R_L = 2k Ω , C_L = 100pF,unity gain		0.4		V/µs

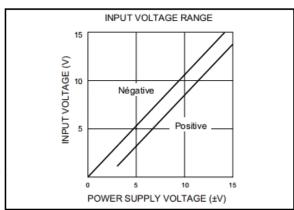


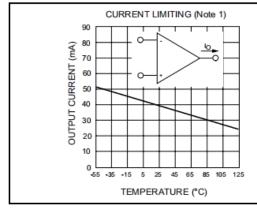
Symbol	Parameter	Min.	Тур.	Max.	Unit
CDD	Gain Bandwidth Product		4.0		NAL 1-
GBP	V_{cc} = 30V, V_{in} = 10mV, R_L = 2k Ω , C_L = 100pF		1.3		MHz
	Total Harmonic Distortion				
TUD	$f = 1kHz$, $A_V = 20dB$, $R_L = 2k\Omega$, $V_o = 2Vpp$,		0.015		%
THD	$C_L = 100 pF, V_{cc} = 30 V$				
	Equivalent Input Noise Voltage		40		nV
e _n	$f = 1kHz$, $R_S = 100\Omega$, $V_{cc} = 30V$		40		$\overline{\sqrt{\text{Hz}}}$
DV _{io}	Input Offset Voltage Drift		7	30	μV/°C
DI _{io}	Input Offset Current Drift		10	200	pA/°C
V _{O1} /V _{O2}	Channel Separation ⁴⁾		400		-ID
VO1/VO2	1kHz ≤ f ≤ 20kHz		120		dB

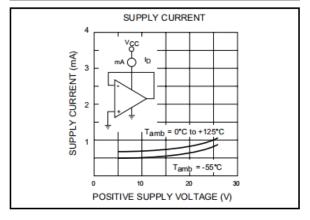
- 1. VO = 1.4V, RS = 0Ω , 5V < VCC + < 30V, 0V < Vic < V CC + 1.5V
- 2. The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output, so no loading charge change exists on the input lines
- 3. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is VCC+ –1.5V, but either or both inputs can go to +32V without damage.
- 4. Due to the proximity of external components insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequences.

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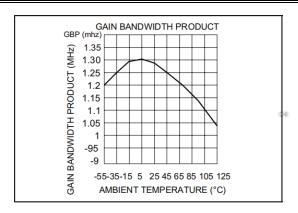


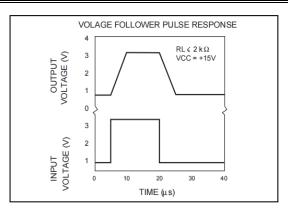


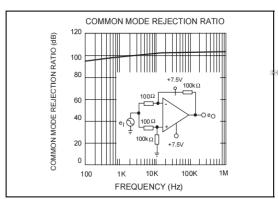


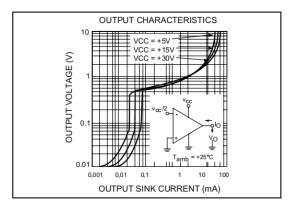


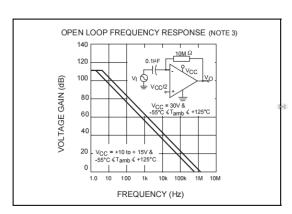


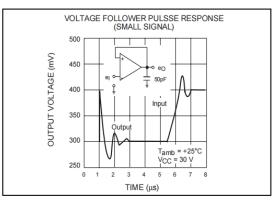


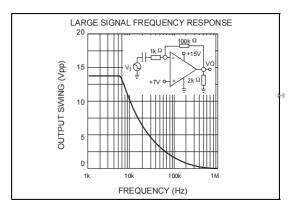


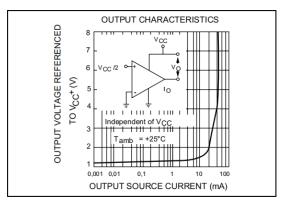




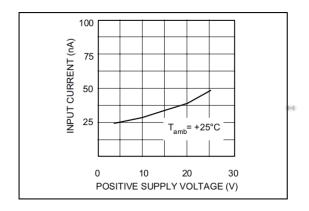


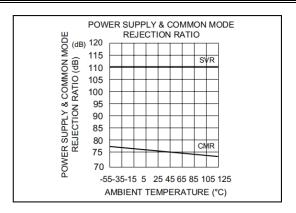


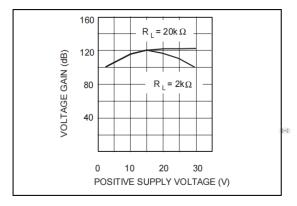


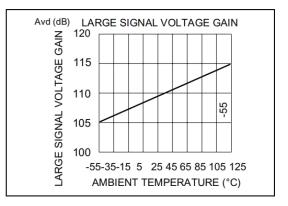








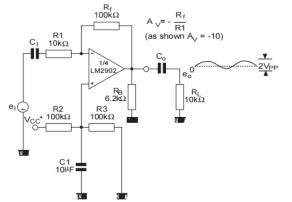




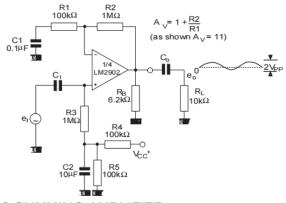


TYPICAL SINGLE - SUPPLY APPLICATIONS

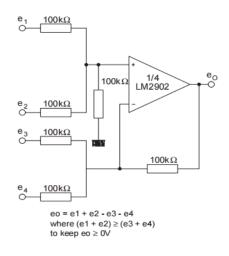
AC COUPLED INVERTING AMPLIFIER



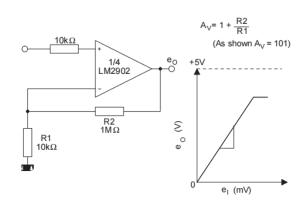
AC COUPLED NON-INVERTING AMPLIFIER



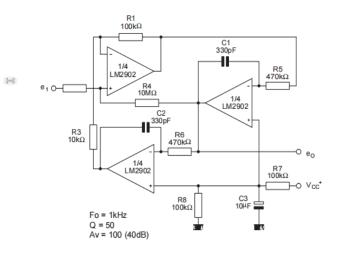
DC SUMMING AMPLIFIER



NON-INVERTING DC GAIN



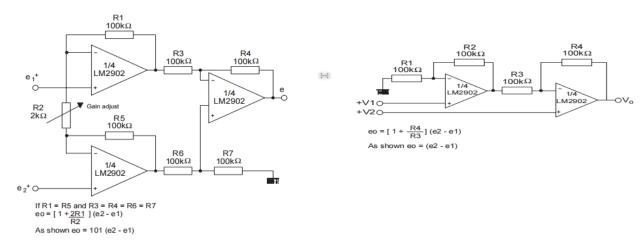
ACTIVER BADPASS FILTER





HIGH INPUT Z ADJUSTABLE GAIN DC INSTRUMENTATION AMPLIFIER

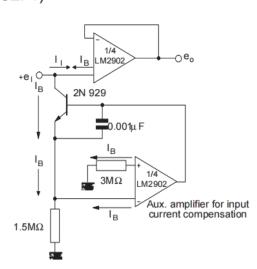
HIGH INPUT Z, DC DIFFERENTIAL AMPLIFIER



LOW DRIFT PEAK DETECTOR

LM2902 1μF 2lB 2N 929 0.001μF 1/4 LM2902 Input current compensation * Polycarbonate or polyethylene

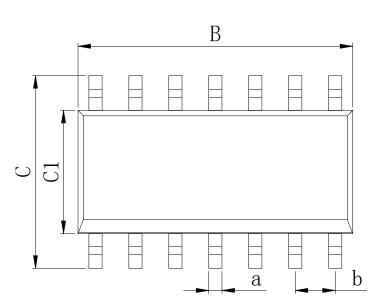
USING SYMMETRICAL AMPLIFIERS TO REDUCE INPUT CURRENT (GENERAL CONCEPT)

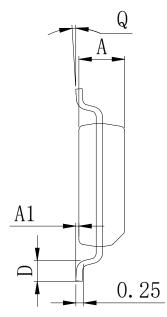




PHYSICAL DIMENSIONS

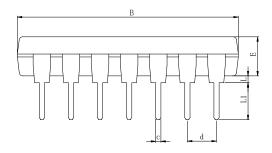
SOP-14

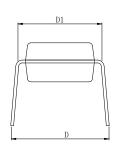


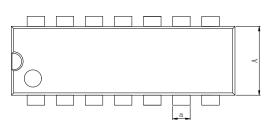


Dimensions In Millimeters(SOP-14)										
Symbol:	Α	A1	В	С	C1	D	Q	а	b	
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1 07 DCC	
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 BSC	

DIP-14





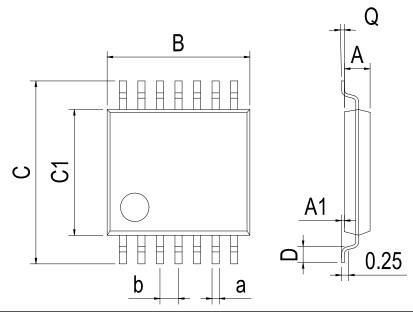


Dimensions In Millimeters(DIP-14)										
Symbol:	Α	В	D	D1	Е	L	L1	а	С	d
Min:	6.10	18.94	8.10	7.42	3.10	0.50	3.00	1.50	0.40	2.54 BSC
Max:	6.68	19.56	10.9	7.82	3.55	0.70	3.60	1.55	0.50	



PHYSICAL DIMENSIONS

TSSOP-14



Dimensions In Millimeters(TSSOP-14)										
Symbol:	A	A1	В	С	C1	D	Q	а	b	
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC	
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.00 BSC	



REVISION HISTORY

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2011-9	New	1-13
V1.1	2023-9	Update encapsulation type、Update Lead Temperature	1、3



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